Quad. Tridirectional Bus Transceiver (with noninverted 3-state outputs) Quad. Tridirectional Bus Transceiver (with inverted 3-state outputs) Quad Tridirectional Bus Transceiver (with noninverted/inverted 3-state outputs)

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Description

These bus transceivers are designed for a synchronous three-way communication between four-line data buses. They give the designer a choice of selecting inverting, noninverting or a combination of inverting and noninverting data paths with 3-state outputs.

The S_0 and S_1 inputs select the bus from which data are to be transferred. The \overline{G} inputs enable the bus or buses to which data are to be transferred. The port for any bus selected for input and any other bus not enabled for output will be at high impedance.

Features

- High Speed Operation
- High Output Current: Fanout of 15 LSTTL Loads
- Wide Operating Voltage: $V_{CC} = 2$ to 6 V
- Low Input Current: 1 µA max
- Low Quiescent Supply Current: I_{CC} (static) = 4 μ A max (Ta = 25°C)



Function Table

Inputs						Transfers Between Buses						
CS	S ₁	S ₀	GΑ	GΒ	GC	HD74HC442	HD74HC443	HD74HC444				
Н	Х	Х	Х	Х	Х	None	None	None				
Х	Н	Н	Х	Х	Х	None	None	None				
Х	Х	Х	Н	Н	Н	None	None	None				
Х	L	L	Х	Н	Н	None	None	None				
Х	L	Н	Н	Х	Н	None	None	None				
Х	Н	L	Н	Н	Х	None	None	None				
L	L	L	Х	L	L	$A\toB,A\toC$	$\overline{A} \to B, \ \overline{A} \to C$	$\overline{A} \to B, \ \overline{A} \to C$				
L	L	Н	L	Х	L	$B\toC,B\toA$	$\overline{B}\toC,\overline{B}\toA$	$B\toC,\overline{B}\toA$				
L	Н	L	L	L	Х	$C \to A, C \to B$	$\overline{C} \to A, \ \overline{C} \to B$	$\overline{C} \rightarrow A, C \rightarrow B$				
L	L	L	Х	L	Н	$A\toB$	$\overline{A} \to B$	$\overline{A} \to B$				
L	L	Н	Н	Х	L	$B\toC$	$\overline{B}\toC$	$B\toC$				
L	Н	L	L	Н	Х	$C\toA$	$\overline{C}\toA$	$\overline{C}\toA$				
L	L	L	Х	Н	L	$A\toC$	$\overline{A} \to C$	$\overline{A} \to C$				
L	L	Н	L	Х	Н	$B\toA$	$\overline{B}\toA$	$\overline{B}\toA$				
L	Н	L	Н	L	Х	$C\toB$	$\overline{C} \to B$	$C\toB$				

Pin Arrangement



Absolute Maximum Ratings

Item	Symbol	Rating	Unit	
Supply voltage range	V _{cc}	–0.5 to +7.0	V	
Input voltage	V _{IN}	–0.5 to V _{cc} + 0.5	V	
Output voltage	V _{OUT}	–0.5 to V _{cc} + 0.5	V	
Output current	I _{OUT}	±35	mA	
DC current drain per V _{cc} GND	I_{CC},I_{GND}	±75	mA	
DC input diode current	I _{IK}	±20	mA	
DC output diode current	Ι _{οκ}	±20	mA	
Power Dissipation per package	P _T	500	mW	
Storage temperature	Tstg	-65 to +150	°C	

Logic Diagram

HD74HC442



HD74HC443



HD74HC444



DC Characteristics

			Ta = 25°C		Ta = −40 to +85°C					
ltem	Symbol	V _{cc} (V)	Min	Тур	Мах	Min	Мах	Unit	Test Condition	าร
Input voltage	V _{IH}	2.0	1.5			1.5		V		
		4.5	3.15	_	_	3.15	_	_		
		6.0	4.2	—	_	4.2	—			
	V _{IL}	2.0	_	_	0.5	_	0.5	V		
		4.5	—	—	1.35	—	1.35	_		
		6.0	—	—	1.8	—	1.8	_		
Output voltage	V _{OH}	2.0	1.9	2.0	_	1.9	_	V	$Vin = V_{IH} \text{ or } V_{IL}$	I _{OH} = -20 μA
		4.5	4.4	4.5	_	4.4	—			
		6.0	5.9	6.0	—	5.9	—			
		4.5	4.18	_	—	4.13	—	_		I _{он} = —6 mА
		6.0	5.68	—	—	5.63	—			I _{он} = -7.8 mА
	V _{OL}	2.0	—	0.0	0.1	—	0.1	V	$Vin = V_{IH} \text{ or } V_{IL}$	I _{oL} = 20 μA
		4.5	_	0.0	0.1	—	0.1	_		
		6.0	—	0.0	0.1	—	0.1	_		
		4.5			0.26	—	0.33	_		$I_{OL} = 6 \text{ mA}$
		6.0	_	_	0.26	—	0.33	_		I _{oL} = 7.8 mA
Off-state output current	I _{oz}	6.0	—	—	±0.5	—	±5.0	μA	$Vin = V_{IH} \text{ or } V_{IL},$ Vout = V _{CC} or C	
Input current	lin	6.0		_	±0.1	_	±1.0	μΑ	$Vin = V_{CC} \text{ or } GN$	ND
Quiescent supply current	I _{cc}	6.0			4.0	—	40	μΑ	Vin = V _{cc} or GN	ND, lout = 0 μA

			Ta = 25°C		Ta = −40 to +85°C				
ltem	Symbol	V_{cc} (V)	Min	Тур	Max	Min	Max	Unit	Test Conditions
Propagation delay	t _{PLH}	2.0	_	_	200	_	250	ns	
time	t _{PHL}	4.5	_	_	40	_	50	_	
		6.0	—	—	34	—	43	_	
Output enable	t _{zH}	2.0	_	_	150	_	190	ns	
time	t _{zL}	4.5	—	—	30	—	38		
		6.0	—	—	26	—	33		
Output disable	t _{HZ}	2.0	—	_	150	—	190	ns	
time	t _{LZ}	4.5	—	—	30	—	38		
		6.0			26	—	33	_	
Output rise/fall	t _{TLH}	2.0	_		60	—	75	ns	
time	t_{THL}	4.5			12	—	15	_	
		6.0			10	—	13	_	
Input capacitance	Cin	_	_	5	10	_	10	pF	

AC Characteristics ($C_L = 50 \text{ pF}$, Input $t_r = t_f = 6 \text{ ns}$)



Unit: mm





Unit: mm



Unit: mm

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